Diode Semiconductor Device - Page 1 of 1



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### Inclosure Material:

Metal

**Overall Length:** 

0.700 inches

## **Overall Diameter:**

1.000 inches

# **Mounting Facility Quantity:**

1

## Mounting Method:

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### Thread Size:

0.313 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

600.0 working peak reverse voltage, peak total value and 420.0 reverse voltage, total rms

#### **Current Rating Per Characteristic:**

100.00 amperes forward current, dc

### **Power Rating Per Characteristic:**

350.0 watts total power dissipation

#### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

#### **Test Data Document:**

05869-720621 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# **Thread Series Designator:**

Unc

#### **Terminal Type And Quantity:**

1 tab, solder lug and 1 case

#### Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

## Fiig:

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